

BC816W series

80 V, 500 mA NPN general-purpose transistors

Rev. 2 — 27 November 2019

Product data sheet

1. General description

NPN general-purpose transistors in a very small SOT323 (SC-70) Surface-Mounted Device (SMD) plastic package.

Table 1. Product overview

Type number	Package		PNP complement:
	Nexperia	JEITA	
BC816-16W	SOT323	SC-70	BC806-16W
BC816-25W			BC806-25W

2. Features and benefits

- High current
- High voltage
- · Two current gain selections
- AEC-Q101 qualified

3. Applications

- · General-purpose switching and amplification
- · 48 V automotive board net

4. Quick reference data

Table 2. Quick reference data

 T_{amb} = 25 °C unless otherwise specified.

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
V_{CEO}	collector-emitter voltage	open base		-	-	80	V
I _C	collector current			-	-	500	mA
I _{CM}	peak collector current	single pulse; t _p ≤ 1 ms		-	-	1	Α
h _{FE}	DC current gain		1				
	BC816-16W	V _{CE} = 1 V; I _C = 100 mA	[1]	100	-	250	
	BC816-25W		[1]	160	-	400	

[1] pulsed; $t_p \le 300 \ \mu s$; $\delta \le 0.02$



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5. Pinning information

Table 3. Pinning

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	В	base] 3	С
2	E	emitter		
3	С	collector		B — [
				Ė
				sym123
			SC-70 (SOT323)	

6. Ordering information

Table 4. Ordering information

Type number Package					
	Name	Description	Version		
BC816-16W	SC70	plastic surface-mounted package; 3 leads	SOT323		
BC816-25W	1				

7. Marking

Table 5. Marking

Type number	Marking code [1]
BC816-16W	2L%
BC816-25W	2M%

[1] % = placeholder for manufacturing site code

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8. Limiting values

Table 6. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

 T_{amb} = 25 °C unless otherwise specified.

Symbol	Parameter	Conditions		Min	Max	Unit
V _{CBO}	collector-base voltage	open emitter	open emitter -		80	V
V _{CEO}	collector-emitter voltage	open base		-	80	V
V _{EBO}	emitter-base voltage	open collector		-	7	V
I _C	collector current			-	500	mA
I _{CM}	peak collector current	single pulse; t _p ≤ 1 ms		-	1	Α
I _{BM}	peak base current	single pulse; t _p ≤ 1 ms		-	200	mA
P _{tot}	total power dissipation	T _{amb} ≤ 25 °C	[1]	-	200	mW
			[2]	-	290	mW
T _j	junction temperature			-	150	°C
T _{amb}	ambient temperature			-55	150	°C
T _{stg}	storage temperature			-65	150	°C

- [1] Device mounted on an FR4 Printed-Circuit-Board (PCB); single-sided copper; tin-plated and standard footprint.
- [2] Device mounted on an FR4 PCB; single-sided copper; tin-plated; mounting pad for collector 1 cm².

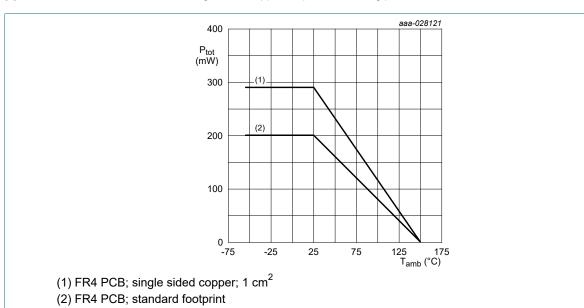


Fig. 1. Power derating curves

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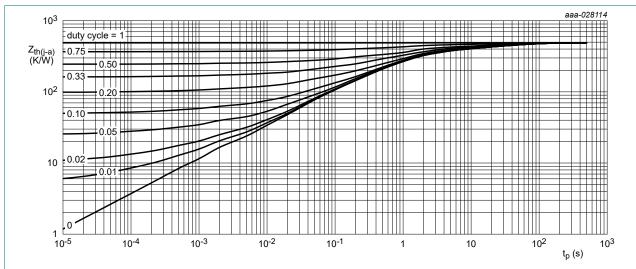
9. Thermal characteristics

Table 7. Thermal characteristics

 T_{amb} = 25 °C unless otherwise specified.

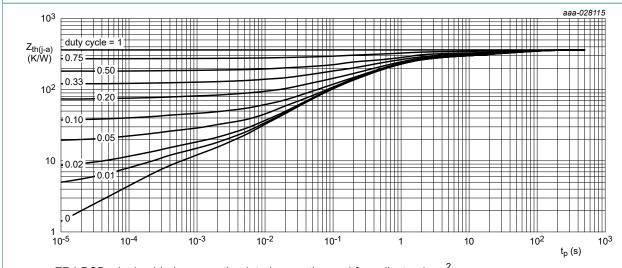
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air	[1]	-	-	625	K/W
			[2]	-	-	431	K/W

- [1] Device mounted on an FR4 PCB; single-sided copper; tin-plated and standard footprint.
- Device mounted on an FR4 PCB; single-sided copper; tin-plated; mounting pad for collector 1 cm².



FR4 PCB; single-sided copper; tin-plated and standard footprint

Fig. 2. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values



FR4 PCB; single-sided copper; tin-plated; mounting pad for collector 1 cm²

Fig. 3. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values

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10. Characteristics

Table 8. Characteristics

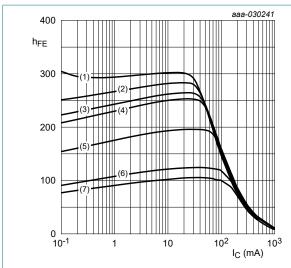
 T_{amb} = 25 °C unless otherwise specified.

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
V _{(BR)CBO}	collector-base breakdown voltage	I _C = 100 μA; I _E = 0 A		80	-		V
$V_{(BR)CEO}$	collector-emitter breakdown voltage	I _C = 2 mA; I _E = 0 A		80	-		V
$V_{(BR)EBO}$	emitter-base breakdown voltage	I _E = 100 μA; I _C = 0 A		7	-		V
I _{CBO}	collector-base	V _{CB} = 64 V; I _E = 0 A		-	-	100	nA
	cut-off current	V _{CB} = 64 V; I _E = 0 A; T _j = 150 °C		-	-	5	μΑ
I _{EBO}	emitter-base cut-off current	V _{EB} = 5.6 V; I _C = 0 A		-	-	100	nA
h _{FE}	DC current gain				'	'	
	BC816-16W	V _{CE} = 1 V; I _C = 100 mA	[1]	100	-	250	
	BC816-25W	V _{CE} = 1 V; I _C = 100 mA	[1]	160	-	400	
		V _{CE} = 2 V; I _C = 500 mA	[1]	30	-	-	
V _{CEsat}	collector-emitter	I _C = 100 mA; I _B = 10 mA	[1]	-	-	150	mV
	saturation voltage	I _C = 500 mA; I _B = 50 mA	[1]	-	-	400	mV
V_{BE}	base-emitter voltage	V _{CE} = 1 V; I _C = 500 mA	[1]	-	-	1.2	V
f _T	transition frequency	V _{CE} = 5 V; I _C = 50 mA; f = 100 MHz		100	-	-	MHz
C _c	collector capacitance	V _{CB} = 10 V; I _E = i _e = 0 A; f = 1 MHz		-	2	-	pF

^[1] pulsed; $t_p \le 300 \ \mu s; \ \delta \le 0.02$

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 $V_{CE} = 1 V$

(1) $T_{amb} = 150 \, ^{\circ}C$

(2) T_{amb} = 125 °C

(3) $T_{amb} = 100 \, ^{\circ}C$

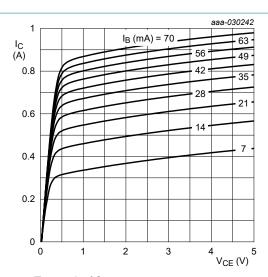
(4) $T_{amb} = 85 \, ^{\circ}C$

(5) $T_{amb} = 25 \, ^{\circ}C$

(6) $T_{amb} = -40 \, ^{\circ}C$

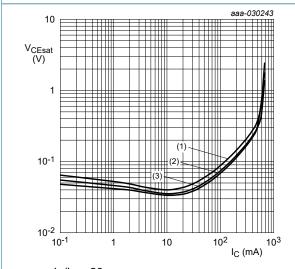
 $(7) T_{amb} = -55 °C$

Fig. 4. BC816-16W: DC current gain as a function of collector current; typical values



 $T_{amb} = 25 \, ^{\circ}C$

Fig. 5. BC816-16W: Collector current as a function of collector-emitter voltage; typical values



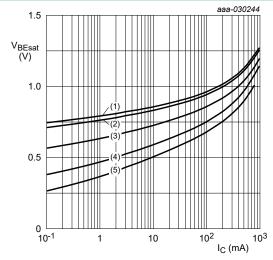
 $I_{\rm C}/I_{\rm B}=20$

(1) $T_{amb} = 100 \, ^{\circ}C$

(2) $T_{amb} = 25 \, ^{\circ}C$

(3) $T_{amb} = -40 \, ^{\circ}C$

Fig. 6. BC816-16W: Collector-emitter saturation voltage as a function of collector current; typical values



 $I_{\rm C}/I_{\rm B} = 10$

(1) $T_{amb} = -55 \, ^{\circ}C$

(2) $T_{amb} = -40 \, ^{\circ}C$

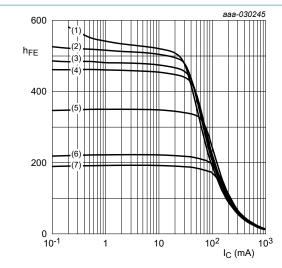
 $(3) T_{amb} = 25 °C$

(4) T_{amb} = 100 °C

(5) $T_{amb} = 150 \, ^{\circ}C$

Fig. 7. BC816-16W: Base-emitter saturation voltage as a function of collector current; typical values

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 $V_{CE} = 1 V$

(1) $T_{amb} = 150 \, ^{\circ}C$

(2) T_{amb} = 125 °C

(3) $T_{amb} = 100 \, ^{\circ}C$

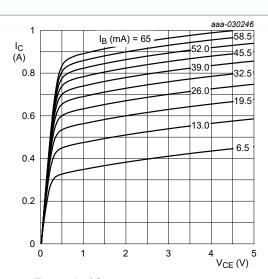
(4) $T_{amb} = 85 \, ^{\circ}C$

(5) $T_{amb} = 25 \, ^{\circ}C$

(6) $T_{amb} = -40 \, ^{\circ}C$

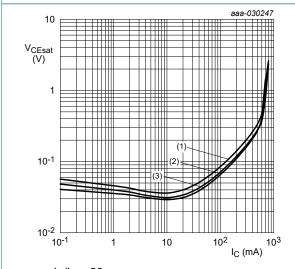
 $(7) T_{amb} = -55 °C$

Fig. 8. BC816-25W: DC current gain as a function of collector current; typical values



 $T_{amb} = 25 \, ^{\circ}C$

Fig. 9. BC816-25W: Collector current as a function of collector-emitter voltage; typical values



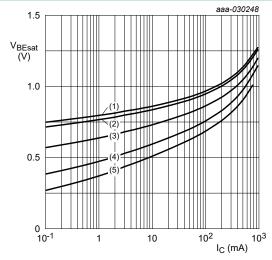
 $I_{\rm C}/I_{\rm B}=20$

(1) $T_{amb} = 100 \, ^{\circ}C$

(2) $T_{amb} = 25 \, ^{\circ}C$

(3) $T_{amb} = -40 \, ^{\circ}C$

Fig. 10. BC816-25W: Collector-emitter saturation voltage as a function of collector current; typical values



 $I_{\rm C}/I_{\rm B} = 10$

(1) $T_{amb} = -55 \, ^{\circ}C$

(2) $T_{amb} = -40 \, ^{\circ}C$

(3) $T_{amb} = 25 \, ^{\circ}C$

(4) T_{amb} = 100 °C

(5) $T_{amb} = 150 \, ^{\circ}C$

Fig. 11. BC816-25W: Base-emitter saturation voltage as a function of collector current; typical values

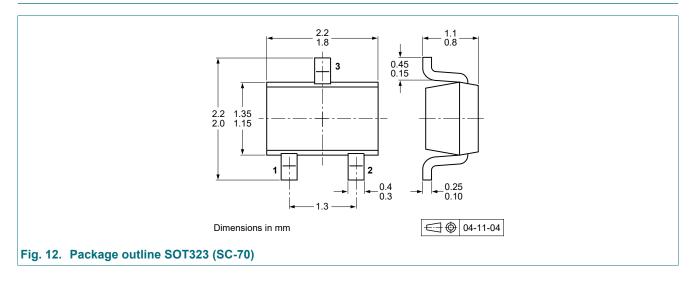
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11. Test information

11.1. Quality information

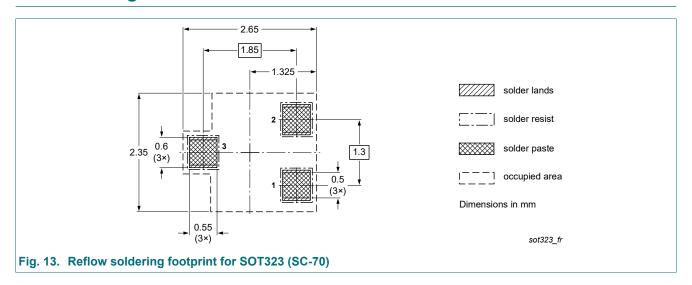
This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard Q101 - Stress test qualification for discrete semiconductors, and is suitable for use in automotive applications.

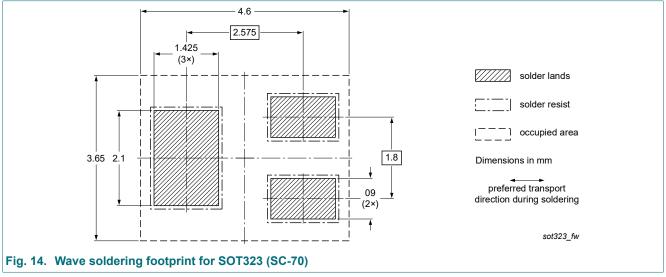
12. Package outline



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13. Soldering





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14. Revision history

Table 9. Revision history

Data sheet ID	Release date	Data sheet status	Change notice	Supersedes				
BC816W_SER v.2	20191127	Product data sheet	-	BC816W_SER v.1				
Modifications:	Product status chang							
BC816W_SER v.1	20190904	Preliminary data sheet	-	-				

15. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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